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DS90CF583/DS90CF584 LVDS 24-Bit Color Flat Panel Display (FPD) Link— 65 MHz

Check for Samples: DS90CF583, DS90CF584

FEATURES

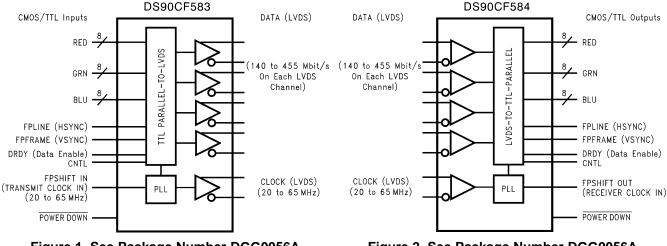
- 20 to 65 MHz Shift Clk Support .
- Up to 227 Mbytes/s Bandwidth
- Cable Size is Reduced to Save Cost
- 290 mV Swing LVDS Devices for Low EMI
- Low Power CMOS Design (< 550 mW typ)
- Power-down Mode Saves Power (< 0.25 mW)

- **PLL Requires No External Components**
- Low Profile 56-Lead TSSOP Package •
- Falling Edge Data Strobe ٠
- Compatible with TIA/EIA-644 LVDS Standard
- Single Pixel Per Clock XGA (1024 x 768) .
- Supports VGA, SVGA, XGA and Higher •
- 1.8 Gbps Throughput

DESCRIPTION

The DS90CF583 transmitter converts 28 bits of CMOS/TTL data into four LVDS (Low Voltage Differential Signaling) data sDS90CF563MTD is no longer available treams. A phase-locked transmit clock is transmitted in parallel with the data streams over a fifth LVDS link. Every cycle of the transmit clock 28 bits of input data are sampled and transmitted. The DS90CF584 receiver converts the LVDS data streams back into 28 bits of CMOS/TTL data. At a transmit clock frequency of 65 MHz, 24 bits of RGB data and 4 bits of LCD timing and control data (FPLINE, FPFRAME, DRDY, CONTROL) are transmitted at a rate of 455 Mbps per LVDS data channel. Using a 65 MHz clock, the data throughput is 227 Mbytes per second. These devices are offered with falling edge data strobes for convenient interface with a variety of graphics and LCD panel controllers.

This chipset is an ideal means to solve EMI and cable size problems associated with wide, high speed TTL interfaces.



BLOCK DIAGRAM

Figure 1. See Package Number DGG0056A

Figure 2. See Package Number DGG0056A

ΑA)

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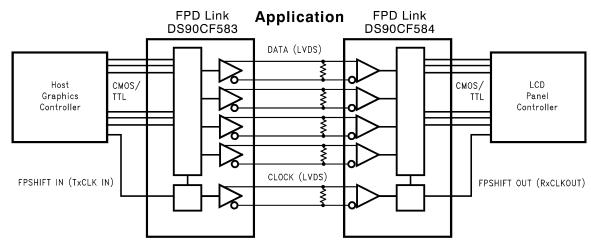
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APPLICATION





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.



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Absolute Maximum Ratings⁽¹⁾⁽²⁾

Voltage (V _{CC})			-0.3V to +6V			
CMOS/TTL Input Voltage						
CMOS/TTL Output Voltage						
LVDS Receiver Input Voltage						
Driver Output Voltage			-0.3V to (V _{CC} + 0.3V)			
Output Short Circuit Duration			Continuous			
n Temperature			+150°C			
e Temperature			-65°C to +150°C			
emperature (Soldering, 4 sec)			+260°C			
um Power Dissipation @ 25°C D	G0056A (TSSOP) Package:	DS90CF583	1.63W			
		DS90CF584	1.61W			
Ρ	ckage Derating:	DS90CF583	12.5 mW/°C above +25°C			
		DS90CF584	12.4 mW/°C above +25°C			
evice does not meet 2000V ESD rating	3).	DS90CF584				

If Military/Aerospace specified devices are required, please contact the TI Sales Office/ Distributors for availability and specifications.
"Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the device should be operated at these limits. "Electrical Characteristics" specify conditions for device operation.

imply that the device should be operated at these limits. "Electrical Characteristics" specify conditions for device operation. (3) ESD Rating: HBM (1.5 k Ω , 100 pF) PLL V_{CC} \geq 1000V All other pins \geq 2000V EIAJ (0 Ω , 200 pF) \geq 150V

Recommended Operating Conditions

	Min	Nom	Max	Units
Supply Voltage (V _{CC})	4.75	5.0	5.25	V
Operating Free Air Temperature (T _A)	-10	+25	+70	°C
Receiver Input Range	0		2.4	V
Supply Noise Voltage (V _{CC})			100	mV _{P-P}

Electrical Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Units
CMOS/T	TL DC SPECIFICATIONS				•	
VIH	High Level Input Voltage		2.0		V_{CC}	V
V _{IL}	Low Level Input Voltage		GND		0.8	V
V _{OH}	High Level Output Voltage	$I_{OH} = -0.4 \text{ mA}$	3.8	4.9		V
V _{OL}	Low Level Output Voltage	$I_{OL} = 2 \text{ mA}$		0.1	0.3	V
V _{CL}	Input Clamp Voltage	I _{CL} = -18 mA		-0.7 9	-1.5	V
I _{IN}	Input Current	V _{IN} = V _{CC} , GND, 2.5V or 0.4V		±5.1	±10	μA
I _{OS}	Output Short Circuit Current	$V_{OUT} = 0V$			-120	mA
LVDS D	RIVER DC SPECIFICATIONS					
V _{OD}	Differential Output Voltage	$R_L = 100\Omega$	250	290	450	mV
ΔV_{OD}	Change in V _{OD} between				35	mV
	Complementary Output States					
V _{CM}	Common Mode Voltage		1.1	1.25	1.37 5	V
ΔV_{CM}	Change in V_{CM} between				35	mV
	Complementary Output States					
V _{OH}	High Level Output Voltage			1.3	1.6	V
V _{OL}	Low Level Output Voltage		0.9	1.01		V
l _{os}	Output Short Circuit Current	$V_{OUT} = 0V, R_L = 100\Omega$		-2.9	-5	mA

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Electrical Characteristics (continued)

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Conditions		Min	Тур	Max	Units
I _{OZ}	Output TRI-STATE Current	Power Down = 0V, V _{OUT} = 0V or V _{CC}			±1	±10	μA
LVDS R	ECEIVER DC SPECIFICATIONS	-					
V _{TH}	Differential Input High Threshold	V _{CM} = +1.2V				+100	mV
V _{TL}	Differential Input Low Threshold			-100			mV
I _{IN}	Input Current	$V_{IN} = +2.4V$	$V_{CC} = 5.5V$			±10	μA
		V _{IN} = 0V				±10	μA
TRANS	MITTER SUPPLY CURRENT		•	-			
I _{CCTW}	Transmitter Supply Current,	$R_{L} = 100\Omega, C_{L} = 5 \text{ pF},$	f = 32.5 MHz		49	63	mA
	Worst Case	Worst Case Pattern	f = 37.5 MHz		51	64	mA
		(Figure 3, Figure 5)	f = 65 MHz		70	84	mA
I _{CCTG}	Transmitter Supply Current,	$R_{L} = 100\Omega, C_{L} = 5 \text{ pF},$	f = 32.5 MHz		40	55	mA
	16 Grayscale	16 Grayscale Pattern	f = 37.5 MHz		41	55	mA
		(Figure 4, Figure 5)	f = 65 MHz		55	67	mA
I _{CCTZ}	Transmitter Supply Current,	Power Down = Low			1	25	μA
	Power Down						
RECEIV	ER SUPPLY CURRENT		· · ·				
I _{CCRW}	Receiver Supply Current,	C _L = 8 pF,	f = 32.5 MHz		64	77	mA
	Worst Case	Worst Case Pattern	f = 37.5 MHz		70	85	mA
		(Figure 3, Figure 6)	f = 65 MHz		110	140	mA
I _{CCRG}	Receiver Supply Current,	$C_L = 8 \text{ pF},$	f = 32.5 MHz		35	55	mA
	16 Grayscale	16 Grayscale Pattern	f = 37.5 MHz		37	55	mA
		(Figure 4, Figure 6)	f = 65 MHz		55	67	mA
I _{CCRZ}	Receiver Supply Current,	Power Down = Low	· · · · · · · · · · · · · · · · · · ·		1	10	μA
	Power Down						

Transmitter Switching Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter		Min	Тур	Max	Units
LLHT	LVDS Low-to-High Transition Time (Figure 5)		0.75	1.5	ns	
LHLT	LVDS High-to-Low Transition Time (Figure 5)			0.75	1.5	ns
TCIT	TxCLK IN Transition Time (Figure 7)				8	ns
TCCS	TxOUT Channel-to-Channel Skew ⁽¹⁾ (Figure 8)				350	ps
TCCD	TxCLK IN to TxCLK OUT Delay @ 25°C, V _{CC} = 5.0V		3.5		8.5	ns
	(Figure 11)					
TCIP	TxCLK IN Period (Figure 9)		15	т	50	ns
TCIH	TxCLK IN High Time (Figure 9)		0.35T	0.5T	0.65T	ns
TCIL	TxCLK IN Low Time (Figure 9)		0.35T	0.5T	0.65T	ns
TSTC	TxIN Setup to TxCLK IN (Figure 9)	f = 65 MHz	5	3.5		ns
THTC	TxIN Hold to TxCLK IN (Figure 9)		2.5	1.5		ns
TPDD	Transmitter Powerdown Delay (Figure 20)				100	ns
TPLLS	Transmitter Phase Lock Loop Set (Figure 13)				10	ms
TPPos0	Transmitter Output Pulse Position 0 (Figure 15)		-0.30	0	0.30	ns
TPPos1	Transmitter Output Pulse Position 1		1.70	1/7 T _{clk}	2.50	ns
TPPos2	Transmitter Output Pulse Position 2		3.60	2/7 T _{clk}	4.50	ns
TPPos3	Transmitter Output Pulse Position 3		5.90	3/7 T _{clk}	6.75	ns

(1) This limit based on bench characterization.



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Transmitter Switching Characteristics (continued)

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Min	Тур	Max	Units	
TPPos4	Transmitter Output Pulse Position 4		8.30	4/7 T _{clk}	9.00	ns
TPPos5	Transmitter Output Pulse Position 5		10.40	5/7 T _{clk}	11.10	ns
TPPos6	Transmitter Output Pulse Position 6		12.70	6/7 T _{clk}	13.40	ns

Receiver Switching Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified.

Symbol	Parameter	Min	Тур	Мах	Units	
CLHT	CMOS/TTL Low-to-High Transition Time (Figure 6)		2.5	4.0	ns	
CHLT	CMOS/TTL High-to-Low Transition Time (Figure 6)			2.0	3.5	ns
RCOP	RxCLK OUT Period		15	Т	50	ns
RCOH	RxCLK OUT High Time	7.8	9		ns	
RCOL	RxCLK OUT Low Time	3.8	5		ns	
RSRC	RxOUT Setup to RxCLK OUTf = 65 MHz		2.5	4.2		ns
RHRC	RxOUT Hold to RxCLK OUT f = 65 MHz		4.0	5.2		ns
RCCD	RxCLK IN to RxCLK OUT Delay @ 25°C, V _{CC} = 5.0V		6.4		10.7	ns
	(Figure 12)					
RPLLS	Receiver Phase Lock Loop Set (Figure 14)				10	ms
RSKM	RxIN Skew Margin ⁽¹⁾ (Figure 16)	V _{CC} = 5V, T _A =25°C	600			ps
RPDD	Receiver Powerdown (Figure 19)				1	μs

(1) Receiver Skew Margin is defined as the valid data sampling region at the receiver inputs. This margin takes into account transmitter output skew (TCCS) and the setup and hold time (internal data sampling window), allowing for LVDS cable skew dependent on type/length and source clock (TxCLK IN) jitter.RSKM ≥ cable skew (type, length) + source clock jitter (cycle to cycle)

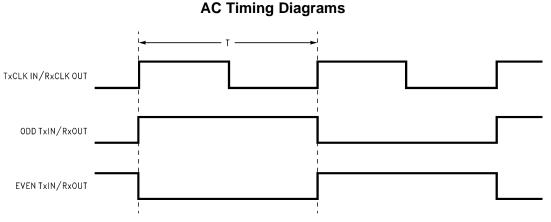
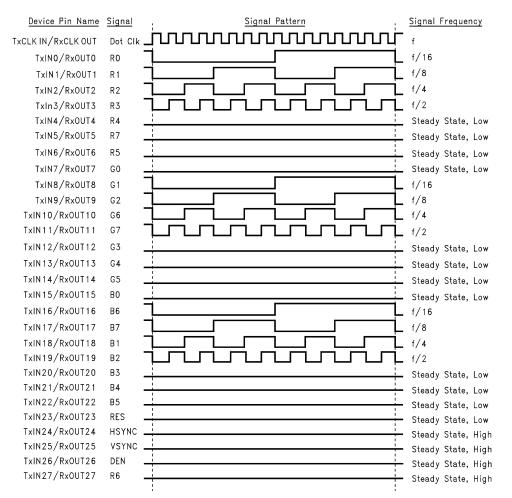


Figure 3. "Worst Case" Test Pattern



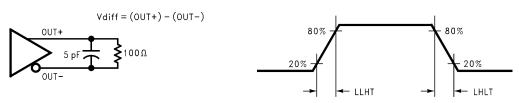
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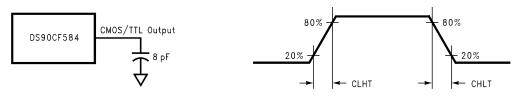


- (1) The worst case test pattern produces a maximum toggling of digital circuits, LVDS I/O and CMOS/TTL I/O.
- (2) The 16 grayscale test pattern tests device power consumption for a "typical" LCD display pattern. The test pattern approximates signal switching needed to produce groups of 16 vertical stripes across the display.
- (3) Figure 3 and Figure 4 show a falling edge data strobe (TxCLK IN/RxCLK OUT).
- (4) Recommended pin to signal mapping. Customer may choose to define differently.

Figure 4. "16 Grayscale" Test Pattern









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ISTRUMENTS

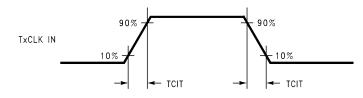
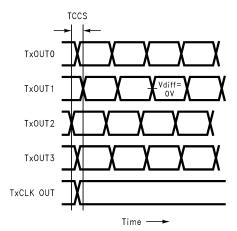


Figure 7. DS90CF583 (Transmitter) Input Clock Transition Time

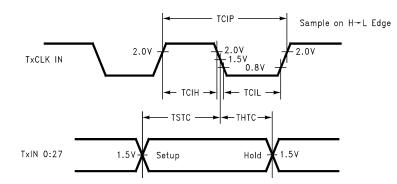


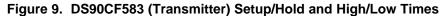
Note:Measurements at Vdiff = 0V

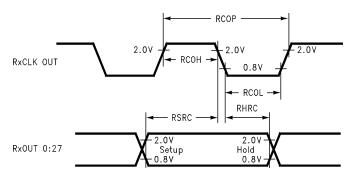
Note: TCSS measured between earliest and latest LVDS edges.

Note: TxCLK Differential High→Low Edge

Figure 8. DS90CF583 (Transmitter) Channel-to-Channel Skew and Pulse Width









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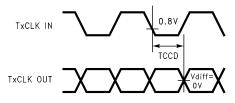


Figure 11. DS90CF583 (Transmitter) Clock In to Clock Out Delay

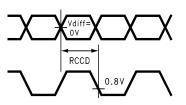


Figure 12. DS90CF584 (Receiver) Clock In to Clock Out Delay

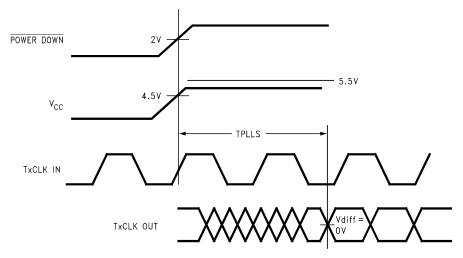


Figure 13. DS90CF583 (Transmitter) Phase Lock Loop Set Time

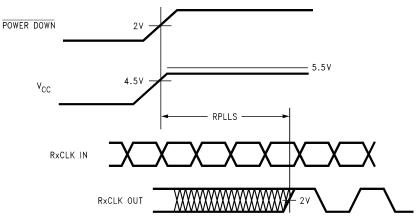


Figure 14. DS90CF584 (Receiver) Phase Lock Loop Set Time

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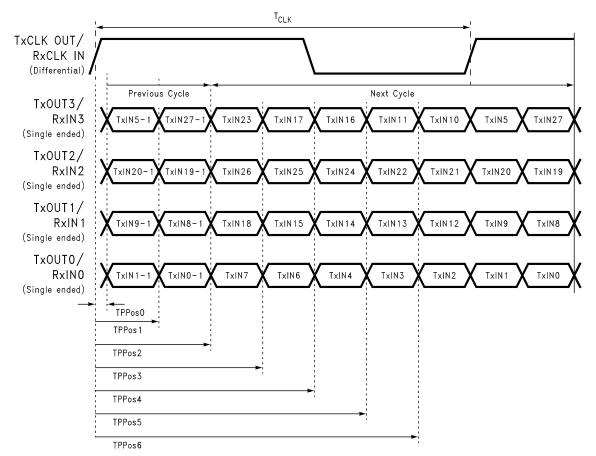
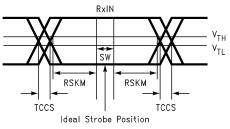
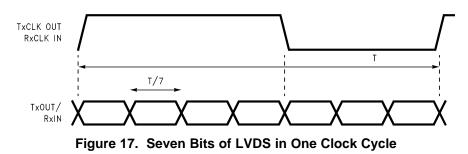


Figure 15. Receiver LVDS Input Pulse Position Measurement



SW—Setup and Hold Time (Internal Data Sampling Window) TCCS—Transmitter Output Skew RSKM ≥ Cable Skew (type, length) + Source Clock Jitter (cycle to cycle) Cable Skew—typically 10 ps–40 ps per foot





TEXAS INSTRUMENTS

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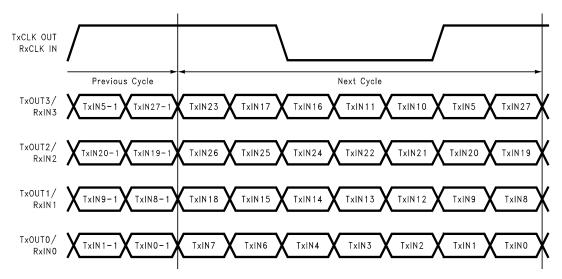


Figure 18. Parallel TTL Data Inputs Mapped to LVDS Outputs (DS90CF583)

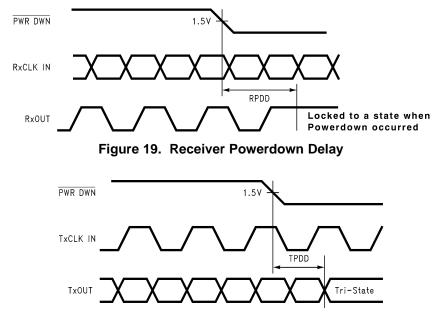


Figure 20. Transmitter Powerdown Delay

Pin Name	I/O	No.	Description
TxIN	I	28	TTL level input. This includes: 8 Red, 8 Green, 8 Blue, and 4 control lines—FPLINE, FPFRAME, DRDY and CNTL (also referred to as HSYNC, VSYNC, Data Enable, CNTL)
TxOUT+	0	4	Positive LVDS differential data output
TxOUT-	0	4	Negative LVDS differential data output
FPSHIFT IN	Т	1	TTL level clock input. The falling edge acts as data strobe
TxCLK OUT+	0	1	Positive LVDS differential clock output
TxCLK OUT-	0	1	Negative LVDS differential clock output
PWR DOWN	I	1	TTL level input. Assertion (low input) TRI-STATES the outputs, ensuring low current at power down
V _{CC}	I	4	Power supply pins for TTL inputs

DS90CF583 Pin Descriptions—FPD Link Transmitter



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DS90CF583 Pin Descriptions—FPD Link Transmitter (continued)

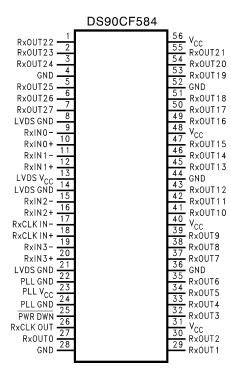
Pin Name	I/O	No.	Description
GND	Ι	5	Ground pins for TTL inputs
PLL V _{CC}	I	1	Power supply pin for PLL
PLL GND	I	2	Ground pins for PLL
LVDS V _{CC}	I	1	Power supply pin for LVDS outputs
LVDS GND	I	3	Ground pins for LVDS outputs

DS90CF584 Pin Descriptions—FPD Link Receiver

Pin Name	I/O	No.	Description
RxIN+	Ι	4	Positive LVDS differential data inputs
RxIN-	Ι	4	Negative LVDS differential data inputs
RxOUT	0	28	TTL level data outputs. This includes: 8 Red, 8 Green, 8 Blue, and 4 control lines—FPLINE, FPFRAME, DRDY and CNTL (also referred to as HSYNC, VSYNC, Data Enable, CNTL)
RxCLK IN+	Ι	1	Positive LVDS differential clock input
RxCLK IN-	Ι	1	Negative LVDS differential clock input
FPSHIFT OUT	0	1	TTL level clock output. The falling edge acts as data strobe
PWR DOWN	Ι	1	TTL level input. Assertion (low input) maintains the receiver outputs in the previous state
V _{CC}	Т	4	Power supply pins for TTL outputs
GND	Т	5	Ground pins for TTL outputs
PLL V _{CC}	Т	1	Power supply for PLL
PLL GND	Ι	2	Ground pin for PLL
LVDS V _{CC}	Ι	1	Power supply pin for LVDS inputs
LVDS GND	Ι	3	Ground pins for LVDS inputs

Connection Diagram

	DS90CF583	
$\begin{array}{c} V_{CC} & 1\\ z \\ T \times IN5 & 3\\ T \times IN6 & 4\\ T \times IN7 & 5\\ GND & 6\\ T \times IN8 & 7\\ T \times IN9 & 8\\ T \times IN9 & 8\\ T \times IN9 & 8\\ T \times IN10 & 9\\ T \times IN11 & 11\\ T \times IN12 & 12\\ T \times IN13 & 13\\ GND & 14\\ T \times IN15 & 16\\ T \times IN16 & 17\\ T \times IN16 & 17\\ T \times IN17 & 19\\ T \times IN18 & 20\\ T \times IN17 & 19\\ T \times IN19 & 21\\ T \times IN18 & 20\\ T \times IN21 & 23\\ T \times IN22 & 23\\ T \times IN22 & 24\\ T \times IN22 & 26\\ T \times IN24 & 28\\ T \times IN25 & 28\\ \end{array}$		56 T×IN4 55 T×IN3 54 T×IN3 52 GND 51 T×IN0 50 T×IN27 49 LVDS GND 47 TxOUT0- 47 TxOUT0+ 46 TxOUT1- 45 TxOUT1+ 44 LVDS VCC 42 TxOUT2- 41 TxOUT2- 41 TxOUT3- 37 TxOUT3+ 36 LVDS GND 35 PLL GND 34 PLL VCC 31 TxCLK IN 30 T×IN26 29 GND



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